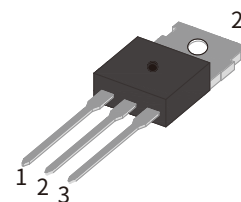


FEATURES

- | High current 12 A RMS current Triac
- | Low thermal resistance
- | High commutation or very high commutation capability



TO-220C

APPLICATIONS

- | General purpose motor control circuits
- | Phase control operations in light dimmers and motor speed controllers
- | Home appliances



Schematic Symbol

APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003

THE MAIN PARAMETERS

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current	12	A
V_{DRM}	Off-state repetitive peak voltage	1200	V
V_{TM}	On-state voltage	1.5	V

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage ($T_j=25^{\circ}\text{C}$)	V_{DRM}	1200	V
Repetitive peak reverse voltage ($T_j=25^{\circ}\text{C}$)	V_{RRM}	1200	V
RMS on-state current ($T_c=100^{\circ}\text{C}$)	$I_{\text{T(RMS)}}$	12	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$)	I_{TSM}	120	
I^2t value for fusing ($t_p=10\text{ms}$)	I^2t	78	A^2S
Critical rate of rise of on-state current ($I_G=2 \cdot I_{\text{GT}}$)	di/dt	50	$\text{A}/\mu\text{s}$
Peak gate current	I_{GM}	4	A
Average gate power dissipation	$P_{\text{G(AV)}}$	1	W
Storage junction temperature range	T_{STG}	$-40 \sim +150$	$^{\circ}\text{C}$
Operating junction temperature range	T_j	$-40 \sim +125$	

ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value				Unit
			TW	SW	CW	BW	
I_{GT}	$V_D=12\text{V}, R_L=33\Omega$	I - II - III	≤ 5	≤ 10	≤ 35	≤ 50	mA
V_{GT}			≤ 1.3				V
V_{GD}	$V_D=V_{\text{DRM}}, R_L=3.3\text{K}\Omega, T_j=125^{\circ}\text{C}$		≥ 0.2				V
I_{H}	$I_T=100\text{mA}$		≤ 15	≤ 20	≤ 40	≤ 60	mA
I_{L}	$I_G=1.2I_{\text{GT}}$	I - III	≤ 20	≤ 30	≤ 50	≤ 80	
		II	≤ 30	≤ 40	≤ 60	≤ 90	
dV_D/dt	$V_D=67\%V_{\text{DRM}}, T_j=125^{\circ}\text{C}$		≥ 100	≥ 200	≥ 500	≥ 1000	$\text{V}/\mu\text{s}$
V_{TM}	$I_{\text{TM}}=17\text{A}, t_p=380\mu\text{s}$		≤ 1.5				V
I_{DRM}	$V_D=V_{\text{DRM}}, V_R=V_{\text{RRM}}$	$T_j=25^{\circ}\text{C}$	≤ 5				μA
I_{RRM}		$T_j=125^{\circ}\text{C}$	≤ 1				mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case(AC)	1.4	°C/W

PARAMETER CHARACTERISTIC CURVE

FIG.1 Maximum power dissipation versus RMS on-state current

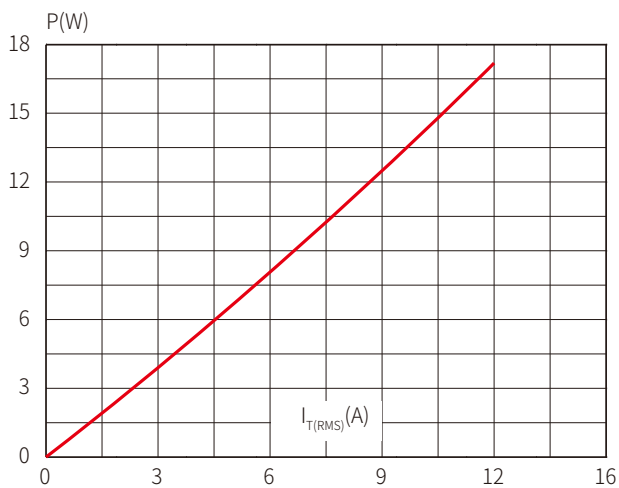


FIG.2: RMS on-state current versus case temperature

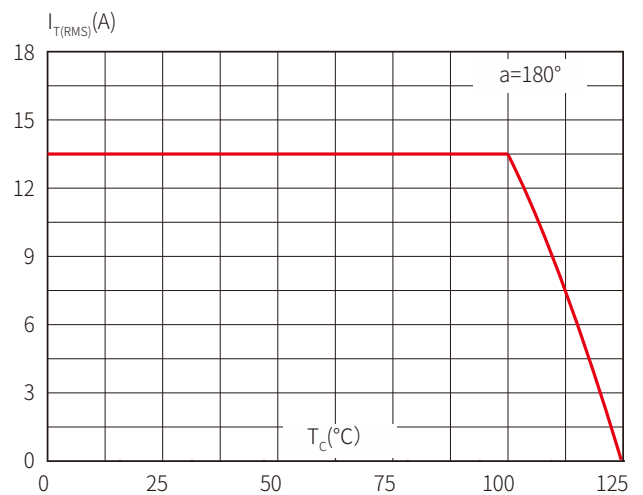


FIG.3: Surge peak on-state current versus number of cycles

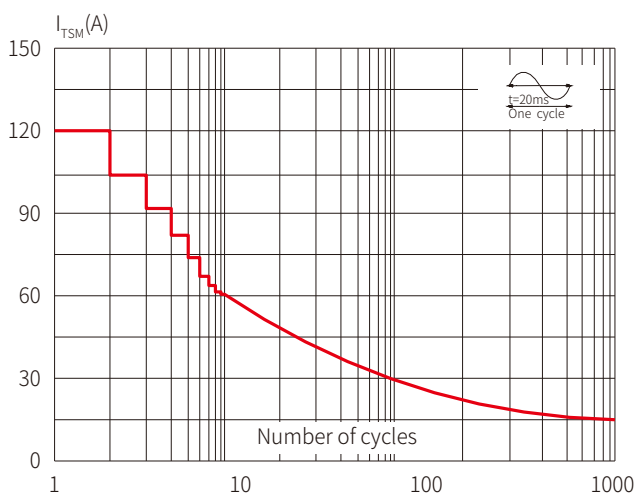


FIG.4 On-state characteristics (maximum values)

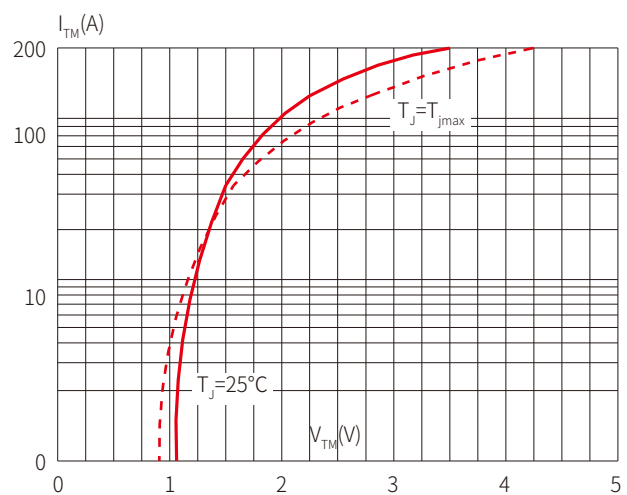


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$ and corresponding value of I^2t ($di/dt < 50\text{A}/\mu\text{s}$)

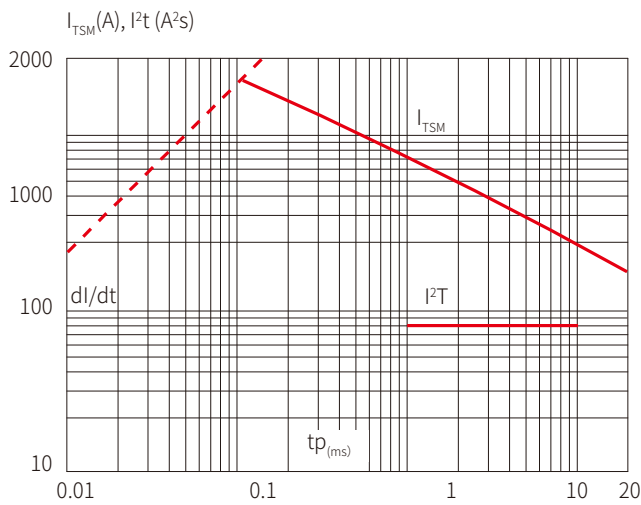


FIG.6 Relative variations of gate trigger current versus junction temperature

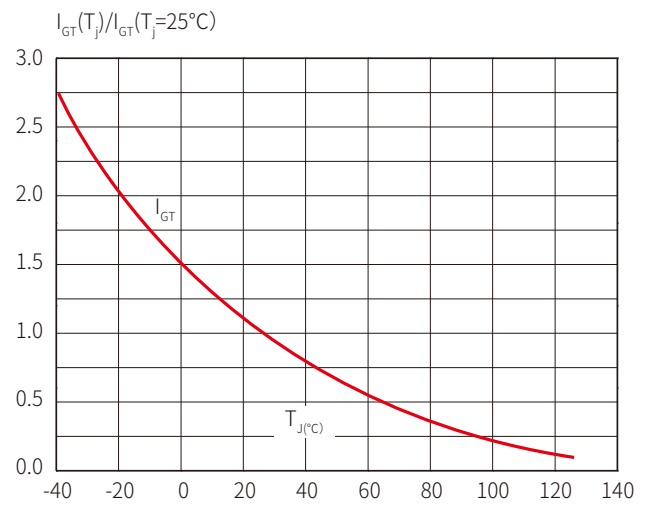


FIG.7 Relative variations of holding current versus junction temperature

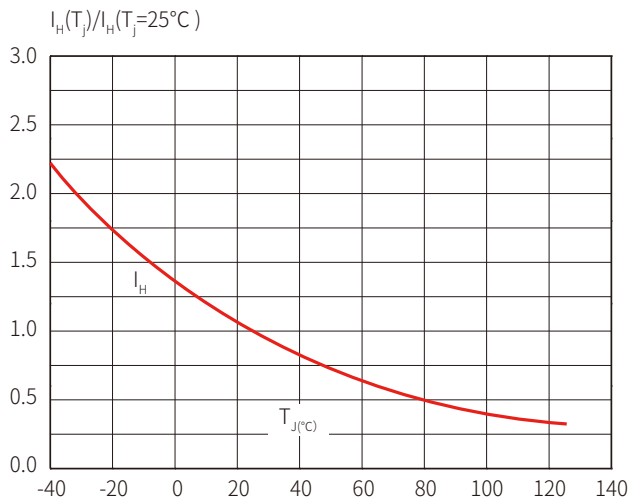
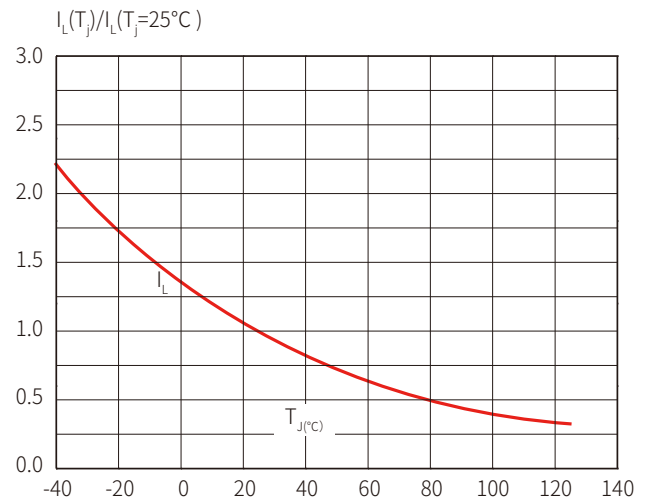
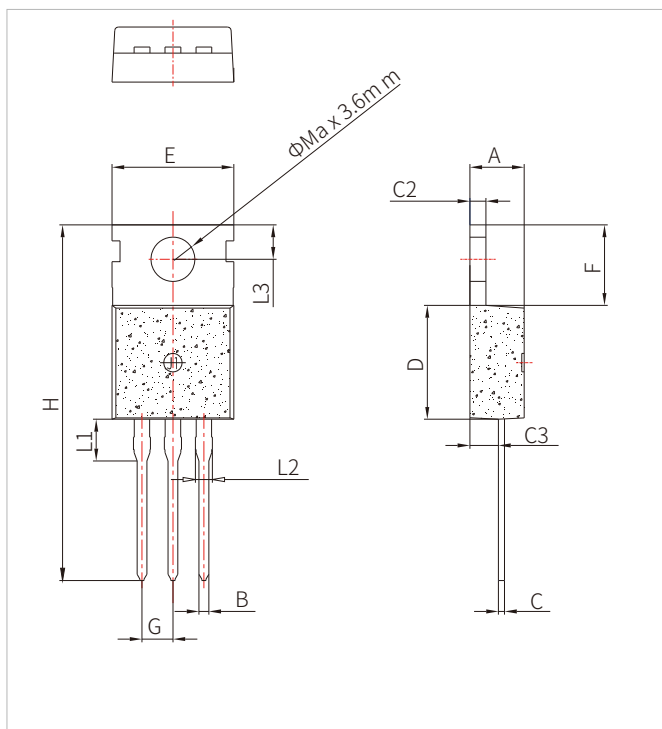


FIG.8 Relative variations of latching current versus junction temperature



TO-220C PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.70	0.169		0.185
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.23		1.32	0.048		0.052
C3	2.20		2.60	0.087		0.102
D	8.80		10.0	0.346		0.394
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G		2.54			0.1	
H	28.0		30.0	1.102		1.181
L1		3.65			0.144	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
Φ		3.6			0.142	

ORDERING INFORMATION

Part Number	Package	Qty/pcs		
		Tube	Inner Box	Carton
STC12A120TW(SW/CW/BW)	TO-220C	50	1000	5000

Headquarters

No.3387 Shendu Road
Pujiang I&E Park
Minhang Shanghai China
201000

Hotline

400-021-5756

Web

<https://www.semiware.com>

Sales Center

Tel: 86-21-3463-7458
Email: sales18@semiware.com

Customer Service

Tel: 86-21-5484-1001
Email: sales17@semiware.com

Technical Support

Tel: 86-21-3463-7654
Email: fae01@semiware.com

Complaint & Suggestions

Tel: 86-21-3463-7172
Ext: 8868
Email: cs03@semiware.com

By QR Code

Website



Wechat

To find your local partner within Semiware' s global website: www.semiware.com

© 2022 Semiware Semiconductor Inc.

The content of this document has been carefully checked and understood. However, neither Semiware nor its subsidiaries assume any liability whatsoever for any errors or inaccuracies of this document and the consequences thereof. Published specifications are subject to change without notice. Product suitability for any area of application must ultimately be determined by the customer. In all cases, products must never be operated outside their published specifications. Semiware does not guarantee the availability of all published products. This disclaimer shall be governed by substantive Chinese law and resulting disputes shall be settled by the courts at the place of business of Semiware. Latest publications and a complete disclaimer can be downloaded from the Semiware website. All trademarks recognized.